

BUK9635-55A

N-channel TrenchMOS logic level FET Rev. 2 — 21 April 2011

Product data sheet

Product profile 1.

1.1 General description

Logic level N-channel enhancement mode Field-Effect Transistor (FET) in a plastic package using TrenchMOS technology. This product has been designed and qualified to the appropriate AEC standard for use in automotive critical applications.

1.2 Features and benefits

■ AEC Q101 compliant

Low conduction losses due to low on-state resistance

1.3 Applications

Automotive and general purpose power switching

1.4 Quick reference data

Table 1. Quick reference data

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|--|--|-----|-----|-----|------|
| V_{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | - | 55 | V |
| I _D | drain current | T _{mb} = 25 °C | - | - | 34 | Α |
| P _{tot} | total power dissipation | | - | - | 85 | W |
| Static characte | eristics | | | | | |
| R _{DSon} | drain-source on-state resistance | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A};$ $T_j = 25 \text{ °C}$ | - | 24 | 32 | mΩ |
| | | $V_{GS} = 5 \text{ V}; I_D = 25 \text{ A};$ $T_j = 25 \text{ °C}$ | - | 26 | 35 | mΩ |
| Avalanche rug | gedness | | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I_D = 14 A; $V_{sup} \le$ 25 V; R_{GS} = 50 Ω ; V_{GS} = 5 V; $T_{j(init)}$ = 25 °C; unclamped | - | - | 49 | mJ |



2. Pinning information

Table 2. Pinning information

| Pin | Symbol | Description | Simplified outline | Graphic symbol |
|-----|--------|--------------------------------------|--------------------|----------------|
| 1 | G | gate | | |
| 2 | D | drain | mb | D |
| 3 | S | source | | |
| mb | D | mounting base; connected to drain | 1 3 | mbb076 S |
| | | | SOT404 (D2PAK) | |

3. Ordering information

Table 3. Ordering information

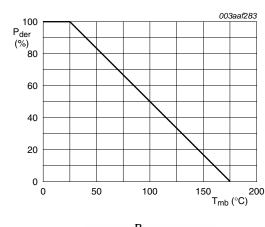
| Type number | Package | | |
|-------------|---------|--|---------|
| | Name | Description | Version |
| BUK9635-55A | D2PAK | plastic single-ended surface-mounted package (D2PAK); 3 leads (one lead cropped) | SOT404 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|----------------------|--|---|-----|-----|------|
| V_{DS} | drain-source voltage | T _j ≥ 25 °C; T _j ≤ 175 °C | - | 55 | V |
| V_{DGR} | drain-gate voltage | $R_{GS} = 20 \text{ k}\Omega$ | - | 55 | V |
| V_{GS} | gate-source voltage | | -10 | 10 | V |
| I _D | drain current | T _{mb} = 100 °C | - | 24 | Α |
| | | T _{mb} = 25 °C | - | 34 | Α |
| I _{DM} | peak drain current | T _{mb} = 25 °C; pulsed | - | 133 | Α |
| P _{tot} | total power dissipation | T _{mb} = 25 °C | - | 85 | W |
| T _{stg} | storage temperature | | -55 | 175 | °C |
| Tj | junction temperature | | -55 | 175 | °C |
| V_{GSM} | peak gate-source voltage | pulsed; $t_p \le 50 \mu s$ | -15 | 15 | V |
| Source-drain | diode | | | | |
| Is | source current | T _{mb} = 25 °C | - | 34 | Α |
| I _{SM} | peak source current | pulsed; T _{mb} = 25 °C | - | 133 | Α |
| Avalanche rug | gedness | | | | |
| E _{DS(AL)S} | non-repetitive drain-source avalanche energy | I_D = 14 A; $V_{sup} \le$ 25 V; R_{GS} = 50 Ω; V_{GS} = 5 V; $T_{j(init)}$ = 25 °C; unclamped | - | 49 | mJ |



$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}C)}} \times 100\,\%$$

Fig 1. Normalized total power dissipation as a function of mounting base temperature

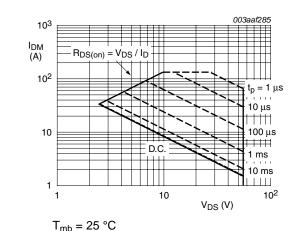
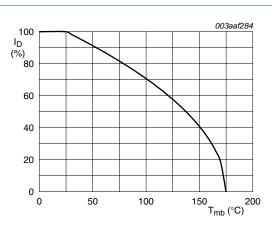


Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage



$$I_{der = \frac{I_D}{I_{D(25^{\circ}C)}} \times} 100\%$$

 $V_{GS} \ge 5 \text{ V}$

Fig 2. Normalized continuous drain current as a function of mounting base temperature

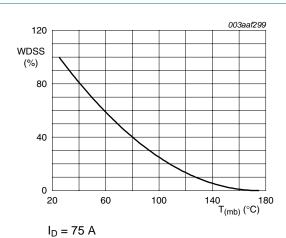
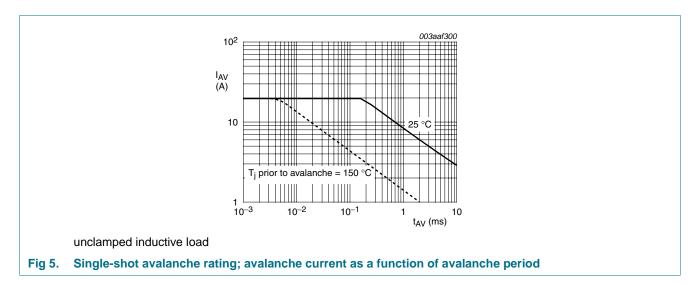


Fig 4. Normalised drain-source non-repetitive avalanche energy as a function of mounting-base temperature



5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|-----------------------|---|------------------------------|-----|-----|-----|------|
| $R_{th(j\text{-}mb)}$ | thermal resistance from junction to mounting base | | - | - | 1.8 | K/W |
| R _{th(j-a)} | thermal resistance from junction to ambient | minimum footprint; FR4 board | - | 50 | - | K/W |

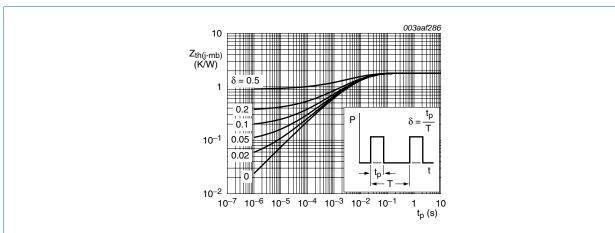


Fig 6. Transient thermal impedance from junction to mounting base as a function of pulse duration

6. Characteristics

Table 6. Characteristics

| Table 6. | Characteristics | | | | | |
|-----------------------------------|------------------------------|--|-----|------|------|------|
| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
| Static cha | racteristics | | | | | |
| V _{(BR)DSS} drain-source | | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ mV}; T_j = 25 \text{ °C}$ | 55 | - | - | V |
| | breakdown voltage | $I_D = 0.25 \text{ mA}; V_{GS} = 0 \text{ mV}; T_j = -55 \text{ °C}$ | 50 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = -55 \text{ °C}$ | - | - | 2.3 | V |
| VO | voltage | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$ | 1 | 1.5 | 2 | V |
| | | $I_D = 1 \text{ mA}; V_{DS} = V_{GS}; T_j = 175 \text{ °C}$ | 0.5 | - | - | V |
| I _{DSS} | drain leakage current | $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | 0.05 | 10 | μΑ |
| | | $V_{DS} = 55 \text{ V}; V_{GS} = 0 \text{ V}; T_j = 175 \text{ °C}$ | - | - | 500 | μΑ |
| I _{GSS} | gate leakage current | $V_{GS} = 10 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 ^{\circ}\text{C}$ | - | 2 | 100 | nΑ |
| | | $V_{GS} = -10 \text{ V}; V_{DS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | 2 | 100 | nΑ |
| R _{DSon} | drain-source on-state | $V_{GS} = 4.5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C}$ | - | 26.5 | 38 | mΩ |
| resistance | resistance | $V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}$ | - | 24 | 32 | mΩ |
| | | V _{GS} = 5 V; I _D = 25 A; T _j = 175 °C | - | - | 70 | mΩ |
| | | $V_{GS} = 5 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ °C}$ | - | 26 | 35 | mΩ |
| Dynamic (| characteristics | | | | | |
| C _{iss} | input capacitance | $V_{GS} = 0 \text{ V}; V_{DS} = 25 \text{ V}; f = 1 \text{ MHz};$ | - | 880 | 1173 | pF |
| C _{oss} | output capacitance | T _j = 25 °C | - | 165 | 198 | pF |
| C_{rss} | reverse transfer capacitance | | - | 111 | 152 | pF |
| t _{d(on)} | turn-on delay time | $V_{DS} = 30 \text{ V}; R_L = 1.2 \Omega; V_{GS} = 5 \text{ V};$ | - | 6 | 9 | ns |
| t _r | rise time | $R_{G(ext)} = 10 \Omega; T_j = 25 °C$ | - | 36 | 55 | ns |
| t _{d(off)} | turn-off delay time | | - | 96 | 134 | ns |
| t _f | fall time | | - | 73 | 102 | ns |
| L _D | internal drain inductance | from upper edge of drain mounting base to centre of die; T _j = 25 °C | - | 2.5 | - | nΗ |
| | | from drain lead 6 mm from package to centre of die; $T_j = 25 ^{\circ}\text{C}$ | - | 4.5 | - | nΗ |
| L _S | internal source inductance | from source lead to source bond pad; $T_j = 25 ^{\circ}\text{C}$ | - | 7.5 | - | nΗ |
| Source-dr | rain diode | | | | | |
| V _{SD} | source-drain voltage | $I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ °C}$ | - | 0.85 | 1.2 | V |
| | | I _S = 34 A; V _{GS} = 0 V; T _j = 25 °C | - | 1.1 | - | V |
| t _{rr} | reverse recovery time | $I_S = 34 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s};$ | - | 36 | - | ns |
| Q _r | recovered charge | $V_{GS} = -10 \text{ V}; V_{DS} = 30 \text{ V}; T_j = 25 \text{ °C}$ | - | 0.07 | - | μC |

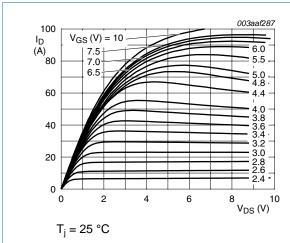


Fig 7. Output characteristics: drain current as a function of drain-source voltage; typical values

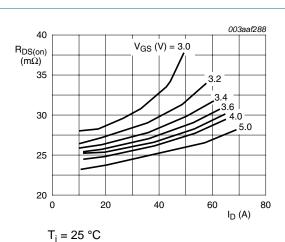


Fig 8. Drain-source on-state resistance as a function of drain current; typical values

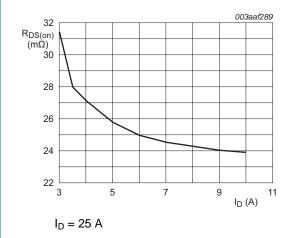


Fig 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

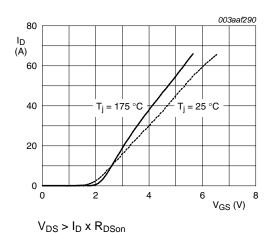


Fig 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

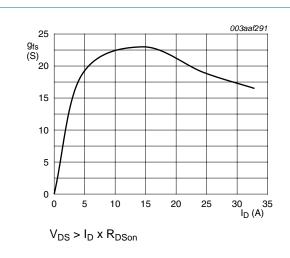


Fig 11. Forward transconductance as a function of drain current; typical values

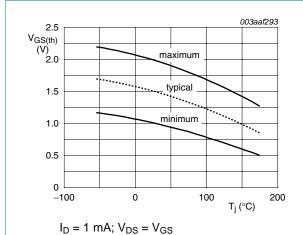
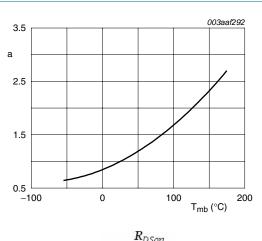


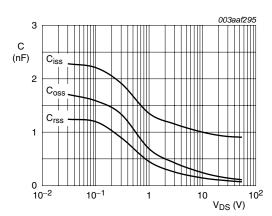
Fig 13. Gate-source threshold voltage as a function of junction temperature



 $a = \frac{Bson}{R_{DSon(25^{\circ}C)}}$

 $I_D = 25 A; V_{GS} = 5 V$

Fig 12. Normalized drain-source on-state resistance factor as a function of junction temperature



 $V_{GS} = 0 V; f = 1 MHz$

Fig 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

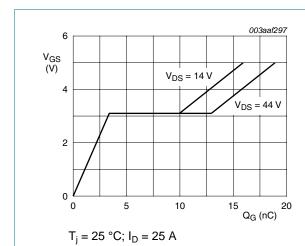


Fig 15. Gate-source voltage as a function of gate charge; typical values

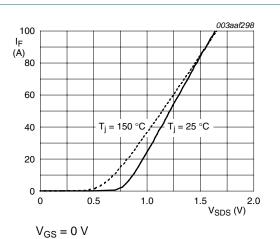


Fig 16. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

7. Package outline

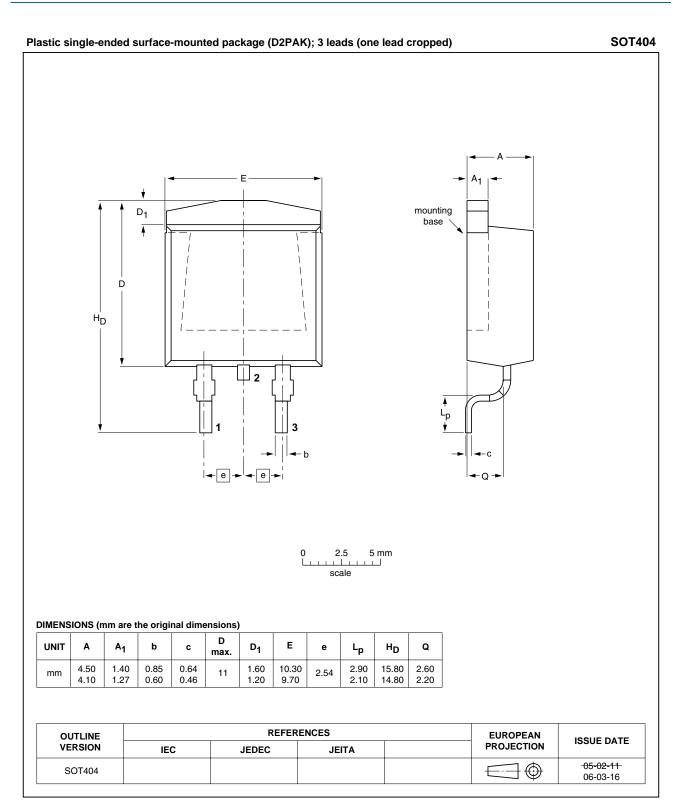


Fig 17. Package outline SOT404 (D2PAK)

8. Revision history

Table 7. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|--------------------|--|--|-----------------------|--------------------|
| BUK9635-55A v.2 | 20110421 | Product data sheet | - | BUK9535_9635-55A_1 |
| Modifications: | | The format of this data sheet has been redesigned to comply with the new identity guide of NXP Semiconductors. | | |
| | Legal texts have b | een adapted to the new c | ompany name where app | oropriate. |
| | Type number BUK | 9635-55A separated from | data sheet BUK9535_96 | 635-55A_1. |
| BUK9535_9635-55A_1 | 20000201 | Product specification | - | - |

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|--------------------------------|--------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

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BUK9635-55A

Nexperia

N-channel TrenchMOS logic level FET

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